	Application No.	Applicant(s)	
Notice of Allowability	10/600,965	AHN ET AL.	
	Examiner	Art Unit	1
	Tuan H. Nguyen	2813	P
The MAILING DATE of this communication appears on the cover sheet with the correspondence address All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308. 1. This communication is responsive to 6/17/04.			
2. ⊠ The allowed claim(s) is/are <u>17-31</u> .			
3. ⊠ The drawings filed on <u>20 June 2003</u> are accepted by the Examiner.			
4.			
 Attachment(s) 1. Notice of References Cited (PTO-892) 2. Notice of Draftperson's Patent Drawing Review (PTO-948) 3. Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 6/20/03, 2/11/04 4. Examiner's Comment Regarding Requirement for Deposit of Biological Material 	5. ☐ Notice of Informal P 6. ☐ Interview Summary Paper No./Mail Dat 8), 7. ☒ Examiner's Amendn 8. ☒ Examiner's Stateme 9. ☐ Other	(PTO-413), e nent/Comment	

Application/Control Number: 10/600,965

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EXAMINER'S AMENDMENT

An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

The application has been amended as follows:

In the title, change: "STRUCTURES, METHODS, AND SYSTEMS FOR FERROELECTRIC MEMORY TRANSISTORS" TO -- METHOD FOR MAKING A FERROELECTRIC MEMORY TRANSISTOR --.

In the specification, page 1,

-line 8, after "2001", insert: --, now U.S. Patent No. 6,586,792 --;

-lines 9-10, delete: "(dockets 303.621US1, 99-0433)";

-line 10, after: "1999", insert: --, now U. S. Patent No. 6,498,362 --;

-line 11, delete: "(docket 99-1036)", and after: "2000", insert: --, now U.S. Pat. No. 6,420,742 --.

This application is in condition for allowance except for the presence of claims 32-42 to an invention non-elected without traverse. Accordingly, claims 32-42 have been cancelled.

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The following is an examiner's statement of reasons for allowance: None of the references of record teaches or suggests the claimed method for forming a ferroelectric transistor including the step of forming a doped zinc-oxide on the doped titanium-oxide layer.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Tuan H. Nguyen whose telephone number is 571-272-1694. The examiner can normally be reached on 9AM-5:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead Jr. can be reached on 571-272-1702. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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Tuan H. Nguyen
Primary Examiner
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